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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	R8C
Core Size	16-Bit
Speed	20MHz
Connectivity	LINbus, SIO, UART/USART
Peripherals	POR, PWM, Voltage Detect, WDT
Number of I/O	25
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	32-LQFP
Supplier Device Package	32-LQFP (7x7)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f212f4dfp-u0">https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f212f4dfp-u0</a>

## 1. Overview

### 1.1 Features

The R8C/2E Group and R8C/2F Group of single-chip MCUs incorporates the R8C/Tiny Series CPU core, employing sophisticated instructions for a high level of efficiency. With 1 Mbyte of address space, and it is capable of executing instructions at high speed. In addition, the CPU core boasts a multiplier for high-speed operation processing.

Power consumption is low, and the supported operating modes allow additional power control. These MCUs also use an anti-noise configuration to reduce emissions of electromagnetic noise and are designed to withstand EMI.

Integration of many peripheral functions, including multifunction timer and serial interface, reduces the number of system components.

Furthermore, the R8C/2F Group has on-chip data flash (1 KB  $\times$  2 blocks).

The difference between the R8C/2E Group and R8C/2F Group is only the presence or absence of data flash. Their peripheral functions are the same.

#### 1.1.1 Applications

Electronic household appliances, office equipment, audio equipment, consumer equipment, etc.

### 1.1.2 Specifications

Tables 1.1 and 1.2 outlines the Specifications for R8C/2E Group and Tables 1.3 and 1.4 outlines the Specifications for R8C/2F Group.

**Table 1.1 Specifications for R8C/2E Group (1)**

Item	Function	Specification
CPU	Central processing unit	R8C/Tiny series core <ul style="list-style-type: none"> <li>• Number of fundamental instructions: 89</li> <li>• Minimum instruction execution time:               <ul style="list-style-type: none"> <li>50 ns (<math>f(XIN) = 20</math> MHz, <math>VCC = 3.0</math> to <math>5.5</math> V)</li> <li>100 ns (<math>f(XIN) = 10</math> MHz, <math>VCC = 2.7</math> to <math>5.5</math> V)</li> </ul> </li> <li>• Multiplier: 16 bits <math>\times</math> 16 bits <math>\rightarrow</math> 32 bits</li> <li>• Multiply-accumulate instruction: 16 bits <math>\times</math> 16 bits + 32 bits <math>\rightarrow</math> 32 bits</li> <li>• Operation mode: Single-chip mode (address space: 1 Mbyte)</li> </ul>
Memory	ROM, RAM	Refer to <b>Table 1.5 Product List for R8C/2E Group</b> .
Power Supply Voltage Detection	Voltage detection circuit	<ul style="list-style-type: none"> <li>• Power-on reset</li> <li>• Voltage detection 2</li> </ul>
I/O Ports	Programmable I/O ports	<ul style="list-style-type: none"> <li>• Input-only: 3 pins</li> <li>• CMOS I/O ports: 25, selectable pull-up resistor</li> <li>• High current drive ports: 8</li> </ul>
Clock	Clock generation circuits	2 circuits: XIN clock oscillation circuit (with on-chip feedback resistor), On-chip oscillator (high-speed, low-speed) (high-speed on-chip oscillator has a frequency adjustment function) <ul style="list-style-type: none"> <li>• Oscillation stop detection: XIN clock oscillation stop detection function</li> <li>• Frequency divider circuit: Dividing selectable 1, 2, 4, 8, and 16</li> <li>• Low power consumption modes:               <ul style="list-style-type: none"> <li>Standard operating mode (high-speed clock, high-speed on-chip oscillator, low-speed on-chip oscillator), wait mode, stop mode</li> </ul> </li> </ul>
Interrupts		<ul style="list-style-type: none"> <li>• External: 4 sources, Internal: 13 sources, Software: 4 sources</li> <li>• Priority levels: 7 levels</li> </ul>
Watchdog Timer		15 bits $\times$ 1 (with prescaler), reset start selectable
Timer	Timer RA	8 bits $\times$ 1 (with 8-bit prescaler) Timer mode (period timer), pulse output mode (output level inverted every period), event counter mode, pulse width measurement mode, pulse period measurement mode
	Timer RB	8 bits $\times$ 1 (with 8-bit prescaler) Timer mode (period timer), programmable waveform generation mode (PWM output), programmable one-shot generation mode, programmable wait one-shot generation mode
	Timer RC	16 bits $\times$ 1 (with 4 capture/compare registers) Timer mode (input capture function, output compare function), PWM mode (output 3 pins), PWM2 mode (PWM output pin)
	Timer RE	8 bits $\times$ 1 Output compare mode
Serial Interface	UART0	Clock synchronous serial I/O/UART $\times$ 1
LIN Module		Hardware LIN: 1 (timer RA, UART0)
A/D Converter		10-bit resolution $\times$ 12 channels, includes sample and hold function
D/A Converter		8-bit resolution $\times$ 2 circuits
Comparator		2 circuits

**Table 1.7 Pin Name Information by Pin Number**

Pin Number	Control Pin	Port	I/O Pin Functions for of Peripheral Modules					
			Interrupt	Timer	Serial Interface	A/D Converter	D/A Converter	Comparator
1		P3_5		(TRCIOD) <sup>(1)</sup>				
2		P3_7		TRA0				
3	RESET							
4	XOUT	P4_7						
5	VSS/AVSS							
6	XIN	P4_6						
7	VCC/AVCC							
8	MODE							
9		P4_5	INT0					
10		P1_7	INT1	TRAIO				
11		P3_6	(INT1) <sup>(1)</sup>					
12		P3_1		TRBO				
13		P5_4		TRCIOD				ACOUT1
14		P5_3		TRCIOA				ACOUT0
15		P1_6			CLK0			
16		P1_5	(INT1) <sup>(1)</sup>	(TRAIO) <sup>(1)</sup>	RXD0			
17		P1_4			TXD0			
18		P1_3	KI3	(TRBO) <sup>(1)</sup>		AN11		
19		P1_2	KI2	TRCIOB		AN10		
20	VREF	P4_2						
21		P1_1	KI1	TRCIOA/ TRCTRG		AN9		
22		P1_0	KI0			AN8		
23		P3_3	INT3	TRCCLK				
24		P3_4		(TRCIOA) <sup>(1)</sup>				
25		P0_7				AN0	DA1	
26		P0_6				AN1	DA0	
27		P0_5				AN2		AVREF0
28		P0_4		TREO		AN3		ACMP0
29		P0_3				AN4		AVREF1
30		P0_2				AN5		ACMP1
31		P0_1				AN6		
32		P0_0				AN7		

NOTE:

1. Can be assigned to the pin in parentheses by a program.

## 1.5 Pin Functions

Table 1.8 list Pin Functions.

**Table 1.8 Pin Functions**

Type	Symbol	I/O Type	Description
Power supply input	VCC, VSS	I	Apply 2.7 V to 5.5 V to the VCC pin. Apply 0 V to the VSS pin.
Analog power supply input	AVCC, AVSS	I	Power supply for the A/D converter. Connect a capacitor between AVCC and AVSS.
Reset input	RESET	I	Input "L" on this pin resets the MCU.
MODE	MODE	I	Connect this pin to VCC via a resistor.
XIN clock input	XIN	I	These pins are provided for XIN clock generation circuit I/O. Connect a ceramic resonator or a crystal oscillator between the XIN and XOUT pins. <sup>(1)</sup> To use an external clock, input it to the XIN pin and leave the XOUT pin open.
XIN clock output	XOUT	O	
INT interrupt input	INT0, INT1, INT3	I	INT interrupt input pins
Key input interrupt	KI0 to KI3	I	Key input interrupt input pins
Timer RA	TRAO	O	Timer RA output pin
	TRAIO	I/O	Timer RA I/O pin
Timer RB	TRBO	O	Timer RB output pin
Timer RC	TRCLK	I	External clock input pin
	TRCTRG	I	External trigger input pin
	TRCIOA, TRCIOB, TRCIO, TRCIOD	I/O	Sharing output-compare output / input-capture input / PWM / PWM2 output pins
Timer RE	TREO	O	Timer RE output pin
Serial interface	CLK0	I/O	Clock I/O pin
	RXD0	I	Receive data input pin
	TXD0	O	Transmit data output pin
Reference voltage input	VREF	I	Reference voltage input pin to A/D converter
A/D converter	AN0 to AN11	I	Analog input pins to A/D converter
D/A converter	DA0 to DA1	O	Output pins from D/A converter
Comparator	AVREF0 to AVREF1	I	Reference voltage input pins to comparator
	ACMP0 to ACMP1	I	Analog voltage input pins to comparator
	ACOUT0 to ACOUT1	O	Comparison result output pins of comparator
I/O port	P0_0 to P0_7, P1_0 to P1_7, P3_1, P3_3 to P3_7, P4_5, P5_3, P5_4	I/O	CMOS I/O ports. Each port has an I/O select direction register, allowing each pin in the port to be directed for input or output individually. Any port set to input can be set to use a pull-up resistor or not by a program. P1_0 to P1_7 also function as LED drive ports.
Input port	P4_2, P4_6, P4_7	I	Input-only ports

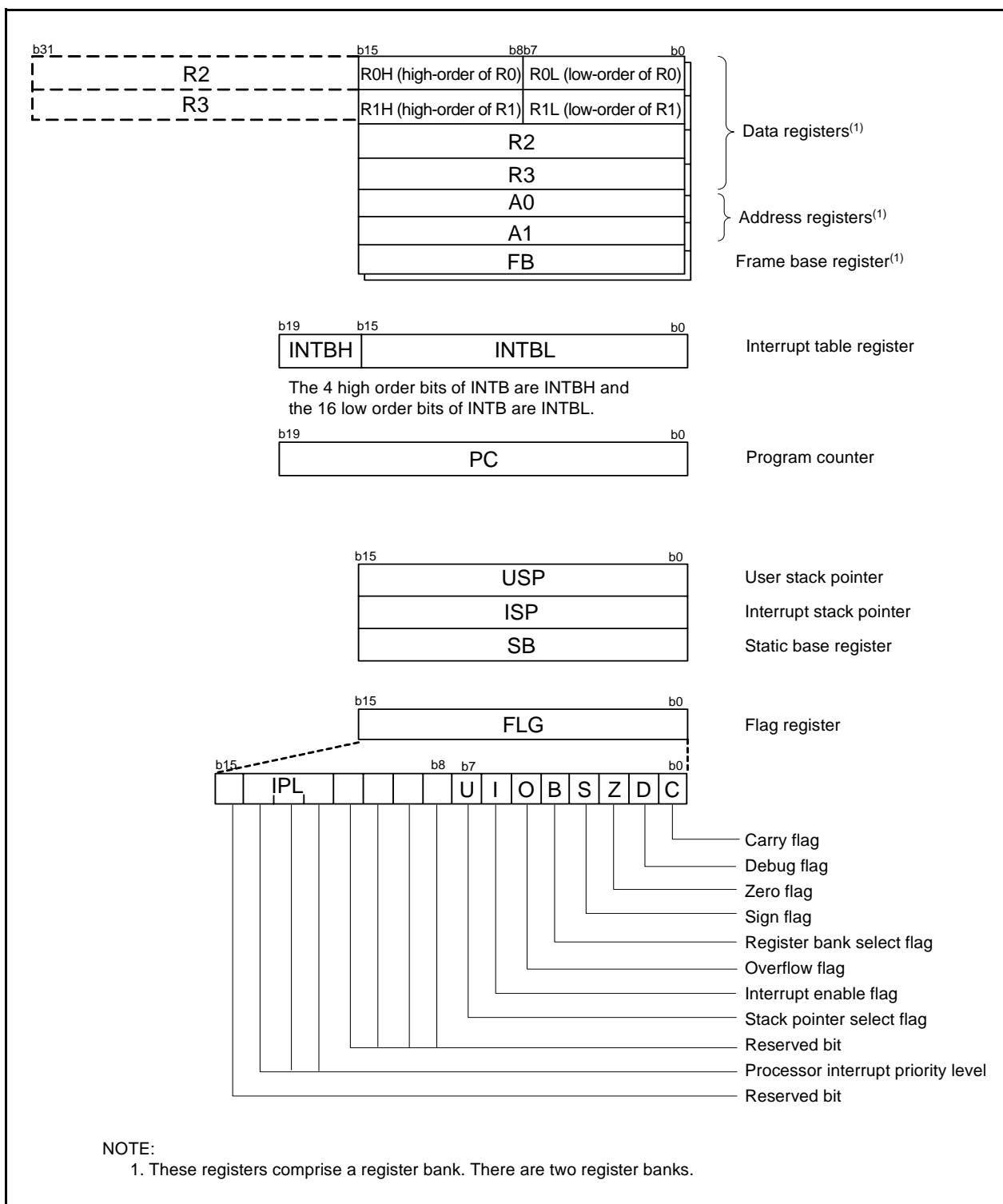
I: Input      O: Output      I/O: Input and output

NOTE:

1. Refer to the oscillator manufacturer for oscillation characteristics.

## 2. Central Processing Unit (CPU)

Figure 2.1 shows the CPU Registers. The CPU contains 13 registers. R0, R1, R2, R3, A0, A1, and FB configure a register bank. There are two sets of register bank.



**Figure 2.1 CPU Registers**

## 2.1 Data Registers (R0, R1, R2, and R3)

R0 is a 16-bit register for transfer, arithmetic, and logic operations. The same applies to R1 to R3. R0 can be split into high-order bits (R0H) and low-order bits (R0L) to be used separately as 8-bit data registers. R1H and R1L are analogous to R0H and R0L. R2 can be combined with R0 and used as a 32-bit data register (R2R0). R3R1 is analogous to R2R0.

## 2.2 Address Registers (A0 and A1)

A0 is a 16-bit register for address register indirect addressing and address register relative addressing. It is also used for transfer, arithmetic, and logic operations. A1 is analogous to A0. A1 can be combined with A0 to be used as a 32-bit address register (A1A0).

## 2.3 Frame Base Register (FB)

FB is a 16-bit register for FB relative addressing.

## 2.4 Interrupt Table Register (INTB)

INTB is a 20-bit register that indicates the start address of an interrupt vector table.

## 2.5 Program Counter (PC)

PC is 20 bits wide and indicates the address of the next instruction to be executed.

## 2.6 User Stack Pointer (USP) and Interrupt Stack Pointer (ISP)

The stack pointers (SP), USP, and ISP, are each 16 bits wide. The U flag of FLG is used to switch between USP and ISP.

## 2.7 Static Base Register (SB)

SB is a 16-bit register for SB relative addressing.

## 2.8 Flag Register (FLG)

FLG is an 11-bit register indicating the CPU state.

### 2.8.1 Carry Flag (C)

The C flag retains carry, borrow, or shift-out bits that have been generated by the arithmetic and logic unit.

### 2.8.2 Debug Flag (D)

The D flag is for debugging only. Set it to 0.

### 2.8.3 Zero Flag (Z)

The Z flag is set to 1 when an arithmetic operation results in 0; otherwise to 0.

### 2.8.4 Sign Flag (S)

The S flag is set to 1 when an arithmetic operation results in a negative value; otherwise to 0.

### 2.8.5 Register Bank Select Flag (B)

Register bank 0 is selected when the B flag is 0. Register bank 1 is selected when this flag is set to 1.

### 2.8.6 Overflow Flag (O)

The O flag is set to 1 when an operation results in an overflow; otherwise to 0.

### **2.8.7 Interrupt Enable Flag (I)**

The I flag enables maskable interrupts.

Interrupt are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

### **2.8.8 Stack Pointer Select Flag (U)**

ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1.

The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

### **2.8.9 Processor Interrupt Priority Level (IPL)**

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7.

If a requested interrupt has higher priority than IPL, the interrupt is enabled.

### **2.8.10 Reserved Bit**

If necessary, set to 0. When read, the content is undefined.



### 3. Memory

#### 3.1 R8C/2E Group

Figure 3.1 is a Memory Map of R8C/2E Group. The R8C/2E group has 1 Mbyte of address space from addresses 00000h to FFFFFh.

The internal ROM is allocated lower addresses, beginning with address 0FFFFh. For example, a 16-Kbyte internal ROM area is allocated addresses 0C000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal RAM is allocated higher addresses beginning with address 00400h. For example, a 1-Kbyte internal RAM area is allocated addresses 00400h to 007FFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.

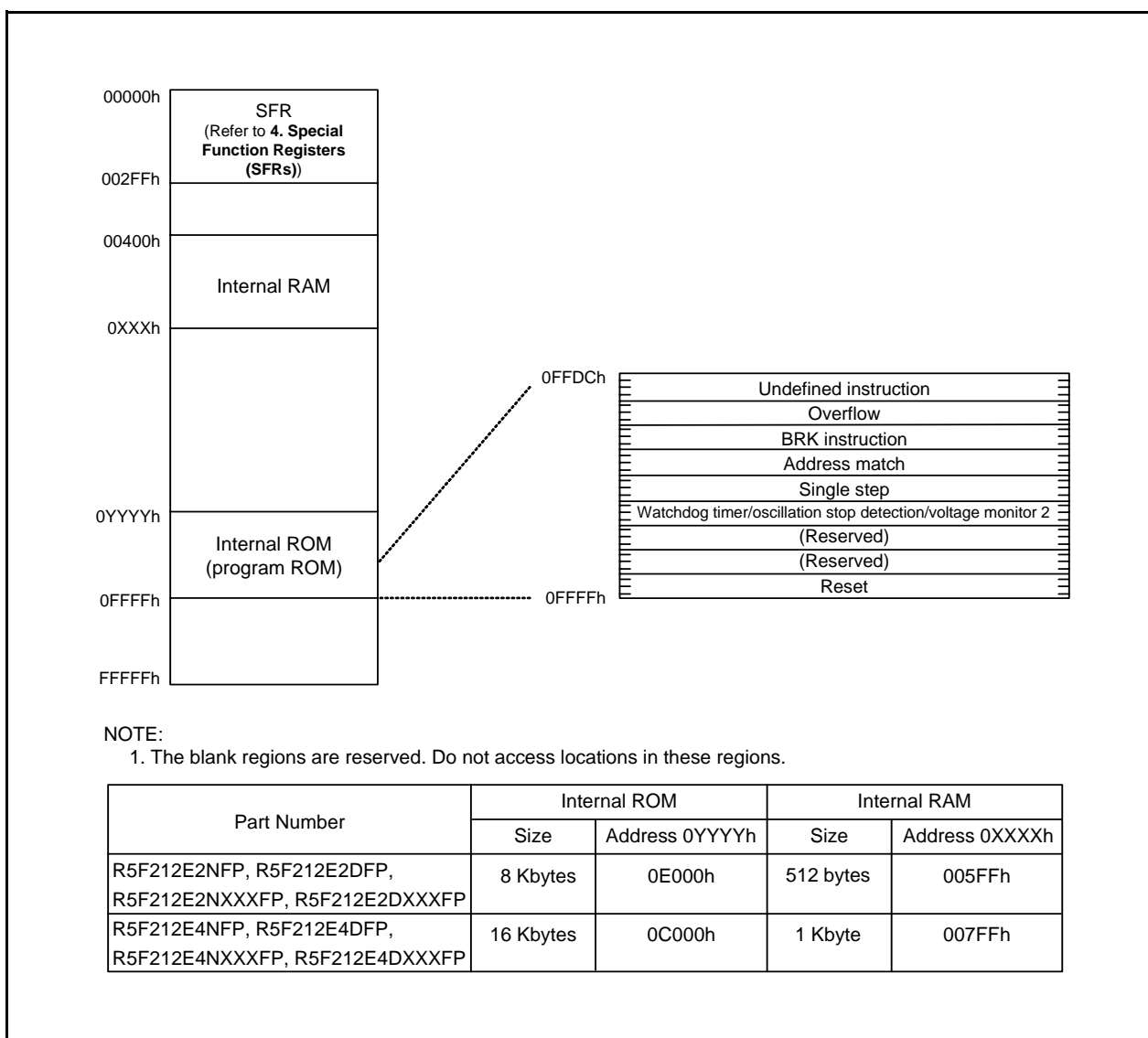


Figure 3.1 Memory Map of R8C/2E Group

### 3.2 R8C/2F Group

Figure 3.2 is a Memory Map of R8C/2F Group. The R8C/2F group has 1 Mbyte of address space from addresses 00000h to FFFFFh.

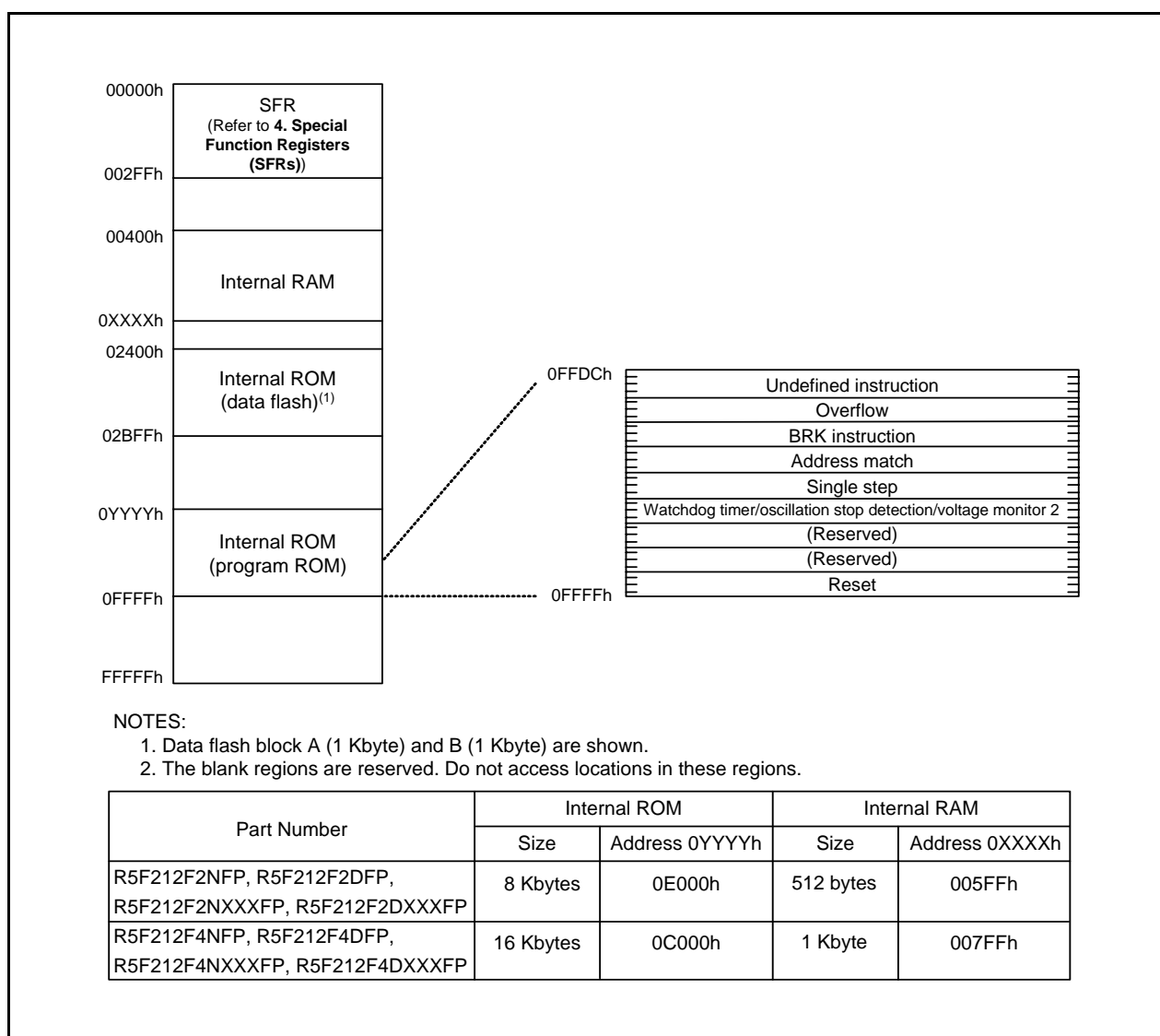
The internal ROM (program ROM) is allocated lower addresses, beginning with address 0FFFFh. For example, a 16-Kbyte internal ROM area is allocated addresses 0C000h to 0FFFFh.

The fixed interrupt vector table is allocated addresses 0FFDCh to 0FFFFh. They store the starting address of each interrupt routine.

The internal ROM (data flash) is allocated addresses 02400h to 02BFFh.

The internal RAM area is allocated higher addresses, beginning with address 00400h. For example, a 1-Kbyte internal RAM is allocated addresses 00400h to 007FFh. The internal RAM is used not only for storing data but also for calling subroutines and as stacks when interrupt requests are acknowledged.

Special function registers (SFRs) are allocated addresses 00000h to 002FFh. The peripheral function control registers are allocated here. All addresses within the SFR, which have nothing allocated are reserved for future use and cannot be accessed by users.



**Figure 3.2 Memory Map of R8C/2F Group**

**Table 4.2 SFR Information (2)<sup>(1)</sup>**

Address	Register	Symbol	After reset
0040h			
0041h			
0042h			
0043h			
0044h			
0045h			
0046h			
0047h	Timer RC Interrupt Control Register	TRCIC	XXXXX000b
0048h			
0049h			
004Ah	Timer RE Interrupt Control Register	TREIC	XXXXX000b
004Bh			
004Ch			
004Dh	Key Input Interrupt Control Register	KUPIC	XXXXX000b
004Eh	A/D Conversion Interrupt Control Register	ADIC	XXXXX000b
004Fh			
0050h			
0051h	UART0 Transmit Interrupt Control Register	S0TIC	XXXXX000b
0052h	UART0 Receive Interrupt Control Register	S0RIC	XXXXX000b
0053h			
0054h			
0055h			
0056h	Timer RA Interrupt Control Register	TRAIC	XXXXX000b
0057h			
0058h	Timer RB Interrupt Control Register	TRBIC	XXXXX000b
0059h	INT1 Interrupt Control Register	INT1IC	XX00X000b
005Ah	INT3 Interrupt Control Register	INT3IC	XX00X000b
005Bh	Comparator 0 Interrupt Control Register	CM0IC	XXXXX000b
005Ch	Comparator 1 Interrupt Control Register	CM1IC	XXXXX000b
005Dh	INT0 Interrupt Control Register	INT0IC	XX00X000b
005Eh			
005Fh			
0060h			
0061h			
0062h			
0063h			
0064h			
0065h			
0066h			
0067h			
0068h			
0069h			
006Ah			
006Bh			
006Ch			
006Dh			
006Eh			
006Fh			
0070h			
0071h			
0072h			
0073h			
0074h			
0075h			
0076h			
0077h			
0078h			
0079h			
007Ah			
007Bh			
007Ch			
007Dh			
007Eh			
007Fh			

X: Undefined

NOTE:

1. The blank regions are reserved. Do not access locations in these regions.

**Table 4.3 SFR Information (3)<sup>(1)</sup>**

Address	Register	Symbol	After reset
0080h			
0081h			
0082h			
0083h			
0084h			
0085h			
0086h			
0087h			
0088h			
0089h			
008Ah			
008Bh			
008Ch			
008Dh			
008Eh			
008Fh			
0090h			
0091h			
0092h			
0093h			
0094h			
0095h			
0096h			
0097h			
0098h			
0099h			
009Ah			
009Bh			
009Ch			
009Dh			
009Eh			
009Fh			
00A0h	UART0 Transmit/Receive Mode Register	U0MR	00h
00A1h	UART0 Bit Rate Register	U0BRG	XXh
00A2h	UART0 Transmit Buffer Register	U0TB	XXh
00A3h			XXh
00A4h	UART0 Transmit/Receive Control Register 0	U0C0	00001000b
00A5h	UART0 Transmit/Receive Control Register 1	U0C1	00000010b
00A6h	UART0 Receive Buffer Register	U0RB	XXh
00A7h			XXh
00A8h			
00A9h			
00AAh			
00ABh			
00ACh			
00ADh			
00AEh			
00AFh			
00B0h			
00B1h			
00B2h			
00B3h			
00B4h			
00B5h			
00B6h			
00B7h			
00B8h			
00B9h			
00BAh			
00BBh			
00BCh			
00BDh			
00BEh			
00BFh			

X: Undefined

NOTE:

1. The blank regions are reserved. Do not access locations in these regions.

**Table 4.5 SFR Information (5)<sup>(1)</sup>**

Address	Register	Symbol	After reset
0100h	Timer RA Control Register	TRACR	00h
0101h	Timer RA I/O Control Register	TRAIOC	00h
0102h	Timer RA Mode Register	TRAMR	00h
0103h	Timer RA Prescaler Register	TRAPRE	FFh
0104h	Timer RA Register	TRA	FFh
0105h			
0106h	LIN Control Register	LINCR	00h
0107h	LIN Status Register	LINST	00h
0108h	Timer RB Control Register	TRBCR	00h
0109h	Timer RB One-Shot Control Register	TRBOCR	00h
010Ah	Timer RB I/O Control Register	TRBIOC	00h
010Bh	Timer RB Mode Register	TRBMR	00h
010Ch	Timer RB Prescaler Register	TRBPRES	FFh
010Dh	Timer RB Secondary Register	TRBSC	FFh
010Eh	Timer RB Primary Register	TRBPR	FFh
010Fh			
0110h			
0111h			
0112h			
0113h			
0114h			
0115h			
0116h			
0117h			
0118h	Timer RE Counter Data Register	TRESEC	00h
0119h	Timer RE Compare Data Register	TREMIN	00h
011Ah			
011Bh			
011Ch	Timer RE Control Register 1	TRECR1	00h
011Dh	Timer RE Control Register 2	TRECR2	00h
011Eh	Timer RE Clock Source Select Register	TRECSR	00001000b
011Fh			
0120h	Timer RC Mode Register	TRCMR	01001000b
0121h	Timer RC Control Register 1	TRCCR1	00h
0122h	Timer RC Interrupt Enable Register	TRCIER	01110000b
0123h	Timer RC Status Register	TRCSR	01110000b
0124h	Timer RC I/O Control Register 0	TRCIOR0	10001000b
0125h	Timer RC I/O Control Register 1	TRCIOR1	10001000b
0126h	Timer RC Counter	TRC	00h
0127h			00h
0128h	Timer RC General Register A	TRCGRA	FFh
0129h			FFh
012Ah	Timer RC General Register B	TRCGRB	FFh
012Bh			FFh
012Ch	Timer RC General Register C	TRCGRC	FFh
012Dh			FFh
012Eh	Timer RC General Register D	TRCGRD	FFh
012Fh			FFh
0130h	Timer RC Control Register 2	TRCCR2	00011111b
0131h	Timer RC Digital Filter Function Select Register	TRCDF	00h
0132h	Timer RC Output Master Enable Register	TRCOER	01111111b
0133h			
0134h			
0135h			
0136h			
0137h			
0138h			
0139h			
013Ah			
013Bh			
013Ch			
013Dh			
013Eh			
013Fh			

X: Undefined

NOTE:

1. The blank regions are reserved. Do not access locations in these regions.

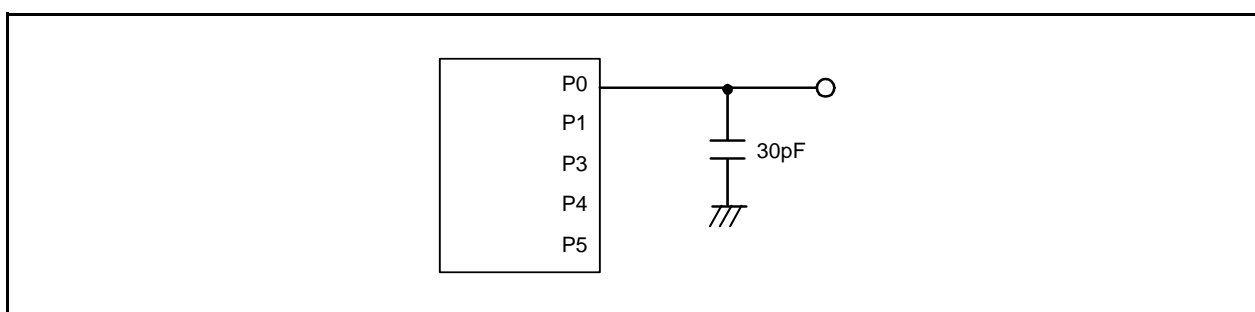


Figure 5.1 Ports P0, P1, and P3 to P5 Timing Measurement Circuit

Table 5.3 A/D Converter Characteristics

Symbol	Parameter		Conditions	Standard			Unit
				Min.	Typ.	Max.	
—	Resolution		$V_{ref} = AV_{CC}$	—	—	10	Bits
—	Absolute accuracy	10-bit mode	$\phi_{AD} = 10 \text{ MHz}$ , $V_{ref} = AV_{CC} = 5.0 \text{ V}$	—	—	$\pm 3$	LSB
		8-bit mode	$\phi_{AD} = 10 \text{ MHz}$ , $V_{ref} = AV_{CC} = 5.0 \text{ V}$	—	—	$\pm 2$	LSB
		10-bit mode	$\phi_{AD} = 10 \text{ MHz}$ , $V_{ref} = AV_{CC} = 3.3 \text{ V}$	—	—	$\pm 5$	LSB
		8-bit mode	$\phi_{AD} = 10 \text{ MHz}$ , $V_{ref} = AV_{CC} = 3.3 \text{ V}$	—	—	$\pm 2$	LSB
$R_{ladder}$	Resistor ladder		$V_{ref} = AV_{CC}$	10	—	40	$k\Omega$
$t_{conv}$	Conversion time	10-bit mode	$\phi_{AD} = 10 \text{ MHz}$ , $V_{ref} = AV_{CC} = 5.0 \text{ V}$	3.3	—	—	$\mu\text{s}$
		8-bit mode	$\phi_{AD} = 10 \text{ MHz}$ , $V_{ref} = AV_{CC} = 5.0 \text{ V}$	2.8	—	—	$\mu\text{s}$
$V_{ref}$	Reference voltage			2.7	—	$AV_{CC}$	V
$V_{IA}$	Analog input voltage <sup>(2)</sup>			0	—	$AV_{CC}$	V
—	A/D operating clock frequency	Without sample and hold	$V_{ref} = AV_{CC} = 2.7 \text{ to } 5.5 \text{ V}$	0.25	—	10	MHz
		With sample and hold	$V_{ref} = AV_{CC} = 2.7 \text{ to } 5.5 \text{ V}$	1	—	10	MHz

## NOTES:

1.  $AV_{CC} = 2.7 \text{ to } 5.5 \text{ V}$  at  $T_{opr} = -20 \text{ to } 85^\circ\text{C}$  (N version) /  $-40 \text{ to } 85^\circ\text{C}$  (D version), unless otherwise specified.
2. When the analog input voltage is over the reference voltage, the A/D conversion result will be 3FFh in 10-bit mode and FFh in 8-bit mode.

Table 5.4 D/A Converter Characteristics

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
—	Resolution		—	—	8	Bit
—	Absolute accuracy		—	—	1.0	%
$t_{su}$	Setup time		—	—	3	$\mu\text{s}$
$R_o$	Output resistor		4	10	20	$k\Omega$
$I_{Vref}$	Reference power input current	(NOTE 2)	—	—	1.5	mA

## NOTES:

1.  $AV_{CC} = 2.7 \text{ to } 5.5 \text{ V}$  at  $T_{opr} = -20 \text{ to } 85^\circ\text{C}$  (N version) /  $-40 \text{ to } 85^\circ\text{C}$  (D version), unless otherwise specified.
2. This applies when one D/A converter is used and the value of the DAi register (i = 0 or 1) for the unused D/A converter is 00h. The resistor ladder of the A/D converter is not included. Also, even if the VCUT bit in the ADCON1 register is set to 0 ( $V_{REF}$  not connected),  $I_{Vref}$  flows into the D/A converters.

**Table 5.5 Comparator Characteristics<sup>(1)</sup>**

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
V <sub>cref</sub>	Comparator reference voltage		0	—	V <sub>CC</sub> –1.2	V
V <sub>cin</sub>	Comparator input voltage		–0.3	—	V <sub>CC</sub> +0.3	V
V <sub>ofs</sub>	Input offset voltage		—	—	±100	mV
T <sub>crsp</sub>	Response time		—	—	200	ns

NOTE:

- V<sub>CC</sub> = 2.7 to 5.5 V at T<sub>opr</sub> = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.

**Table 5.6 Flash Memory (Program ROM) Electrical Characteristics**

Symbol	Parameter	Conditions	Standard			Unit
			Min.	Typ.	Max.	
—	Program/erase endurance <sup>(2)</sup>	R8C/2E Group	100 <sup>(3)</sup>	—	—	times
		R8C/2F Group	1,000 <sup>(3)</sup>	—	—	times
—	Byte program time		—	50	400	μs
—	Block erase time		—	0.4	9	s
t <sub>d</sub> (SR-SUS)	Time delay from suspend request until suspend		—	—	97+CPU clock × 6 cycles	μs
—	Interval from erase start/restart until following suspend request		650	—	—	μs
—	Interval from program start/restart until following suspend request		0	—	—	ns
—	Time from suspend until program/erase restart		—	—	3+CPU clock × 4 cycles	μs
—	Program, erase voltage		2.7	—	5.5	V
—	Read voltage		2.7	—	5.5	V
—	Program, erase temperature		0	—	60	°C
—	Data hold time <sup>(7)</sup>	Ambient temperature = 55°C	20	—	—	year

NOTES:

- V<sub>CC</sub> = 2.7 to 5.5 V at T<sub>opr</sub> = 0 to 60°C, unless otherwise specified.
- Definition of programming/erasure endurance  
The programming and erasure endurance is defined on a per-block basis.  
If the programming and erasure endurance is n (n = 100 or 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.  
However, the same address must not be programmed more than once per erase operation (overwriting prohibited).
- Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
- In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erase count of each block and limit the number of erase operations to a certain number.
- If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
- Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
- The data hold time includes time that the power supply is off or the clock is not supplied.

**Table 5.11 High-speed On-Chip Oscillator Circuit Electrical Characteristics**

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO40M	High-speed on-chip oscillator frequency temperature • supply voltage dependence	V <sub>CC</sub> = 4.75 V to 5.25 V 0°C ≤ T <sub>opr</sub> ≤ 60°C <sup>(2)</sup>	39.2	40	40.8	MHz
		V <sub>CC</sub> = 3.0 V to 5.5 V −20°C ≤ T <sub>opr</sub> ≤ 85°C <sup>(2)</sup>	38.8	40	41.2	MHz
		V <sub>CC</sub> = 3.0 V to 5.5 V −40°C ≤ T <sub>opr</sub> ≤ 85°C <sup>(2)</sup>	38.4	40	41.6	MHz
		V <sub>CC</sub> = 2.7 V to 5.5 V −20°C ≤ T <sub>opr</sub> ≤ 85°C <sup>(2)</sup>	38	40	42	MHz
		V <sub>CC</sub> = 2.7 V to 5.5 V −40°C ≤ T <sub>opr</sub> ≤ 85°C <sup>(2)</sup>	37.6	40	42.4	MHz
		V <sub>CC</sub> = 5.0 V ±10% −20°C ≤ T <sub>opr</sub> ≤ 85°C <sup>(2)</sup>	38.8	40	40.8	MHz
		V <sub>CC</sub> = 5.0 V ±10% −40°C ≤ T <sub>opr</sub> ≤ 85°C <sup>(2)</sup>	38.4	40	40.8	MHz
	High-speed on-chip oscillator frequency when correction value in FRA7 register is written to FRA1 register	V <sub>CC</sub> = 5.0 V, T <sub>opr</sub> = 25°C	—	36.864	—	MHz
		V <sub>CC</sub> = 2.7 V to 5.5 V −20°C ≤ T <sub>opr</sub> ≤ 85°C	−3%	—	3%	%
—	Value in FRA1 register after reset		08h	—	F7h	—
—	Oscillation frequency adjustment unit of high-speed on-chip oscillator	Adjust FRA1 register (value after reset) to −1	—	+0.3	—	MHz
—	Oscillation stability time		—	10	100	μs
—	Self power consumption at oscillation	V <sub>CC</sub> = 5.0 V, T <sub>opr</sub> = 25°C	—	400	—	μA

## NOTES:

1. V<sub>CC</sub> = 2.7 to 5.5 V, T<sub>opr</sub> = −20 to 85°C (N version) / −40 to 85°C (D version), unless otherwise specified.
2. These standard values show when the FRA1 register value after reset is assumed.

**Table 5.12 Low-speed On-Chip Oscillator Circuit Electrical Characteristics**

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
fOCO-S	Low-speed on-chip oscillator frequency		30	125	250	kHz
—	Oscillation stability time		—	10	100	μs
—	Self power consumption at oscillation	V <sub>CC</sub> = 5.0 V, T <sub>opr</sub> = 25°C	—	15	—	μA

## NOTE:

1. V<sub>CC</sub> = 2.7 to 5.5 V, T<sub>opr</sub> = −20 to 85°C (N version) / −40 to 85°C (D version), unless otherwise specified.

**Table 5.13 Power Supply Circuit Timing Characteristics**

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
t <sub>d</sub> (P-R)	Time for internal power supply stabilization during power-on <sup>(2)</sup>		1	—	2000	μs
t <sub>d</sub> (R-S)	STOP exit time <sup>(3)</sup>		—	—	150	μs

## NOTES:

1. The measurement condition is V<sub>CC</sub> = 2.7 to 5.5 V and T<sub>opr</sub> = 25°C.
2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

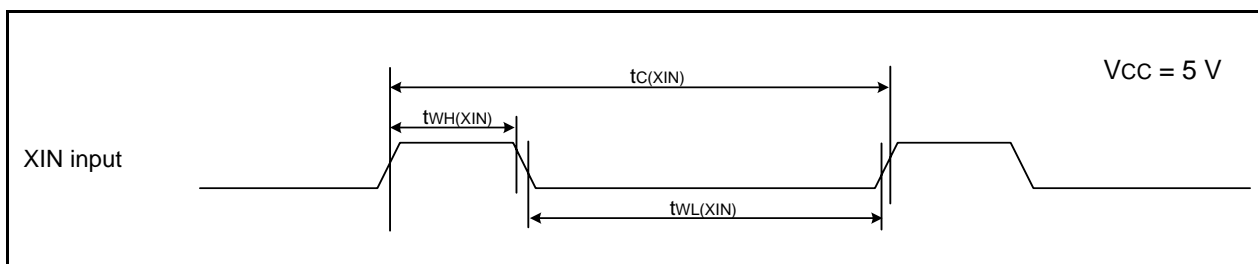


**Table 5.15 Electrical Characteristics (2) [V<sub>CC</sub> = 5 V]**  
**(T<sub>opr</sub> = –20 to 85°C (N version) / –40 to 85°C (D version), unless otherwise specified.)**

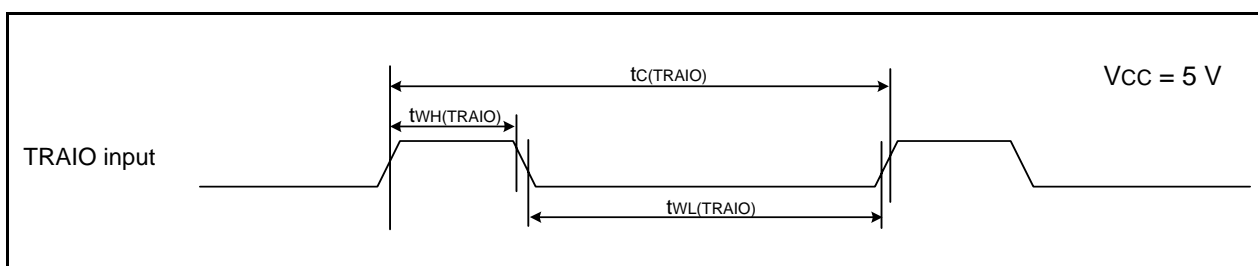
Symbol	Parameter		Condition	Standard			Unit
				Min.	Typ.	Max.	
Icc	Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are Vss	High-speed clock mode	XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	10	17	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	9	15	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division	–	6	–	mA
			XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	5	–	mA
			XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	4	–	mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	2.5	–	mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	10	15	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	4	–	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division	–	5.5	10	mA
			XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8	–	2.5	–	mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1	–	130	300	μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = 0 VCA20 = 1	–	25	75	μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = 0 VCA20 = 1	–	23	60	μA
		Stop mode	XIN clock off, Topr = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = 0	–	0.8	3.0	μA
			XIN clock off, Topr = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = 0	–	1.2	–	μA

**Timing Requirements****(Unless Otherwise Specified:  $V_{CC} = 5\text{ V}$ ,  $V_{SS} = 0\text{ V}$  at  $T_{opr} = 25^{\circ}\text{C}$ ) [ $V_{CC} = 5\text{ V}$ ]****Table 5.16 XIN Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(XIN)}$	XIN input cycle time	50	–	ns
$t_{WH(XIN)}$	XIN input "H" width	25	–	ns
$t_{WL(XIN)}$	XIN input "L" width	25	–	ns

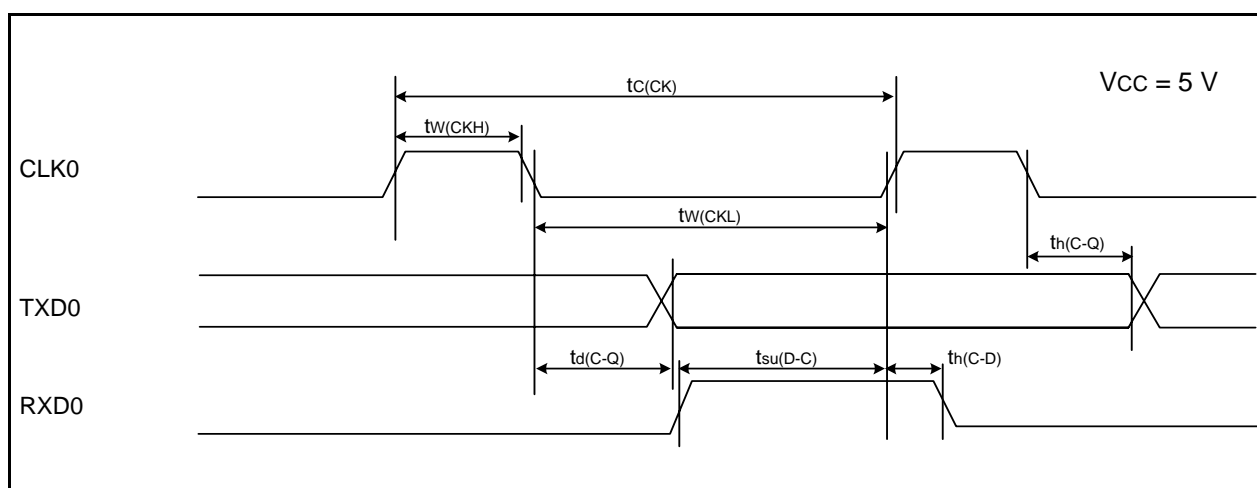
**Figure 5.4 XIN Input Timing Diagram when  $V_{CC} = 5\text{ V}$** **Table 5.17 TRAIO Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TRAIO)}$	TRAIO input cycle time	100	–	ns
$t_{WH(TRAIO)}$	TRAIO input "H" width	40	–	ns
$t_{WL(TRAIO)}$	TRAIO input "L" width	40	–	ns

**Figure 5.5 TRAIO Input Timing Diagram when  $V_{CC} = 5\text{ V}$**

**Table 5.18 Serial Interface**

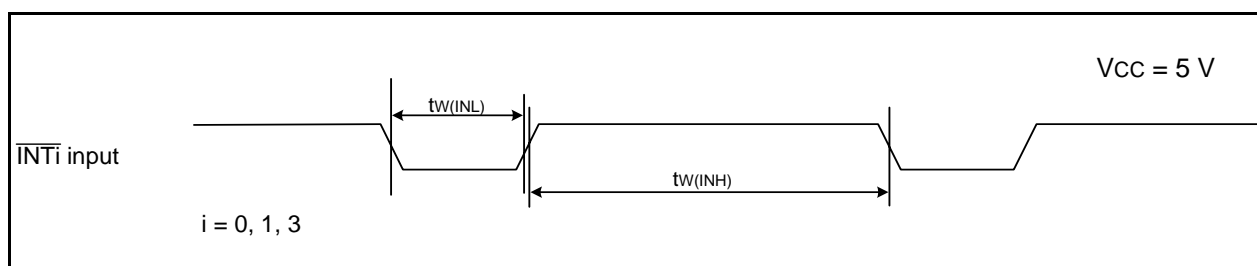
Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(CK)}$	CLK0 input cycle time	200	—	ns
$t_{w(CKH)}$	CLK0 input "H" width	100	—	ns
$t_{w(CKL)}$	CLK0 input "L" width	100	—	ns
$t_{d(C-Q)}$	TXD0 output delay time	—	50	ns
$t_{h(C-Q)}$	TXD0 hold time	0	—	ns
$t_{su(D-C)}$	RXD0 input setup time	50	—	ns
$t_{h(C-D)}$	RXD0 input hold time	90	—	ns

**Figure 5.6 Serial Interface Timing Diagram when Vcc = 5 V****Table 5.19 External Interrupt  $\overline{INTi}$  ( $i = 0, 1, 3$ ) Input**

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(INH)}$	$\overline{INTi}$ input "H" width	250 <sup>(1)</sup>	—	ns
$t_{w(INL)}$	$\overline{INTi}$ input "L" width	250 <sup>(2)</sup>	—	ns

**NOTES:**

1. When selecting the digital filter by the  $\overline{INTi}$  input filter select bit, use an  $\overline{INTi}$  input HIGH width of either (1/digital filter clock frequency  $\times$  3) or the minimum value of standard, whichever is greater.
2. When selecting the digital filter by the  $\overline{INTi}$  input filter select bit, use an  $\overline{INTi}$  input LOW width of either (1/digital filter clock frequency  $\times$  3) or the minimum value of standard, whichever is greater.

**Figure 5.7 External Interrupt  $\overline{INTi}$  Input Timing Diagram when Vcc = 5 V**

**Table 5.20 Electrical Characteristics (3) [V<sub>CC</sub> = 3 V]**

Symbol	Parameter		Condition		Standard			Unit
					Min.	Typ.	Max.	
V <sub>OH</sub>	Output "H" voltage	Except P1_0 to P1_7, XOUT	I <sub>OH</sub> = -1 mA		V <sub>CC</sub> - 0.5	-	V <sub>CC</sub>	V
		P1_0 to P1_7	Drive capacity HIGH	I <sub>OH</sub> = -2 mA	V <sub>CC</sub> - 0.5	-	V <sub>CC</sub>	V
			Drive capacity LOW	I <sub>OH</sub> = -1 mA	V <sub>CC</sub> - 0.5	-	V <sub>CC</sub>	V
		XOUT	Drive capacity HIGH	I <sub>OH</sub> = -0.1 mA	V <sub>CC</sub> - 0.5	-	V <sub>CC</sub>	V
			Drive capacity LOW	I <sub>OH</sub> = -50 μA	V <sub>CC</sub> - 0.5	-	V <sub>CC</sub>	V
V <sub>OL</sub>	Output "L" voltage	Except P1_0 to P1_7, XOUT	I <sub>OL</sub> = 1 mA		-	-	0.5	V
		P1_0 to P1_7	Drive capacity HIGH	I <sub>OL</sub> = 2 mA	-	-	0.5	V
			Drive capacity LOW	I <sub>OL</sub> = 1 mA	-	-	0.5	V
		XOUT	Drive capacity HIGH	I <sub>OL</sub> = 0.1 mA	-	-	0.5	V
			Drive capacity LOW	I <sub>OL</sub> = 50 μA	-	-	0.5	V
V <sub>T+</sub> -V <sub>T-</sub>	Hysteresis	INT0, INT1, INT3, KI0, KI1, KI2, KI3, TRAIO, RXD0, CLK0			0.1	0.3	-	V
		RESET			0.1	0.4	-	V
I <sub>IH</sub>	Input "H" current		V <sub>I</sub> = 3 V, V <sub>CC</sub> = 3 V		-	-	4.0	μA
I <sub>IL</sub>	Input "L" current		V <sub>I</sub> = 0 V, V <sub>CC</sub> = 3 V		-	-	-4.0	μA
R <sub>PULLUP</sub>	Pull-up resistance		V <sub>I</sub> = 0 V, V <sub>CC</sub> = 3 V		66	160	500	kΩ
R <sub>FXIN</sub>	Feedback resistance	XIN			-	3.0	-	MΩ
V <sub>RAM</sub>	RAM hold voltage		During stop mode		1.8	-	-	V

## NOTE:

- V<sub>CC</sub> = 2.7 to 3.3 V at T<sub>opr</sub> = -20 to 85°C (N version) / -40 to 85°C (D version), f<sub>(XIN)</sub> = 10 MHz, unless otherwise specified.

**Table 5.21 Electrical Characteristics (4) [V<sub>CC</sub> = 3 V]**  
**(T<sub>opr</sub> = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)**

Symbol	Parameter	Condition	Standard			Unit
			Min.	Typ.	Max.	
I <sub>CC</sub>	Power supply current (V <sub>CC</sub> = 2.7 to 3.3 V) Single-chip mode, output pins are open, other pins are V <sub>SS</sub>	High-speed clock mode	XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division			mA
			XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8			mA
		High-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator on f <sub>OCO</sub> = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division			mA
			XIN clock off High-speed on-chip oscillator on f <sub>OCO</sub> = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8			mA
		Low-speed on-chip oscillator mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1			μA
		Wait mode	XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock operation VCA27 = VCA26 = 0 VCA20 = 1			μA
			XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz While a WAIT instruction is executed Peripheral clock off VCA27 = VCA26 = 0 VCA20 = 1			μA
		Stop mode	XIN clock off, T <sub>opr</sub> = 25°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = 0			μA
			XIN clock off, T <sub>opr</sub> = 85°C High-speed on-chip oscillator off Low-speed on-chip oscillator off CM10 = 1 Peripheral clock off VCA27 = VCA26 = 0			μA